NSN 5962-01-236-5871

Memory Microcircuit - Page 1 of 1



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Body Length:

0.440 inches

Body Width:

0.275 inches

Body Height:

0.065 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

W/buffered output and hermetically sealed and bipolar and 3-state output and burn in

Inclosure Material:

Ceramic

Inclosure Configuration:

Flat pack

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

100.00 nanoseconds propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Test Data Document:

88818-a574a244 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

16 flat leads

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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